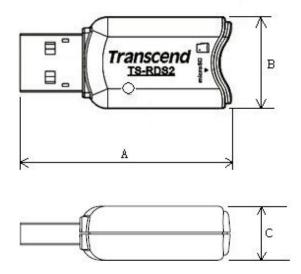
### **Description**

TS-RDS2 is a USB 2.0 Compact Card Reader. It is a small device specifically designed for fast and easy data transfer. The Card Reader accepts the direct insertion of  $\mathbf{microSD}^{\mathsf{TM}}$  Memory Cards.

### **Features**

- Fully Compliant with the Hi-Speed USB 2.0 specification
- Supports the direct input of Memory Card: microSD<sup>™</sup>
- Hi-Speed Data transfer rates up to 480Mb/s
- USB powered (no external power or battery needed)

### **Placement**



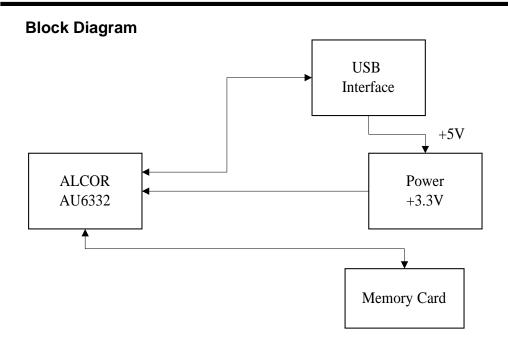
#### **Dimensions**

Side	Millimeters	Inches
Α	44.00 ± 1.00	1.73 ± 0.04
В	19.00 ± 1.00	$0.75 \pm 0.04$
С	11.00 ± 1.00	$0.43 \pm 0.04$

### **System Requirements**

• Desktop or notebook computer with a working USB por

- One of the following Operating Systems:
  - o Windows® Me
  - o Windows® 2000
  - o Windows® XP
  - o Windows Vista TM
  - o Mac<sup>™</sup> OS 9.0, or later
  - Linux<sup>™</sup> Kernel 2.4.2, or later



### **Pinouts**

Pin No.	Pin Name
01	VCC
02	USB-
03	USB+
04	VSS

# **Pin Identification**

Symbol	Function
USB-	USB differential signal:
USB+	The pairs are used to transmit
	Data/Address/Command
VSS	Ground
VCC	USB Power Input

# TS-RDS2

# **Absolute Maximum Ratings**

SYMBOL	PARAMETER	RATING	UNITS
V <sub>DDHM</sub>	Power Supply	-0.3 to V <sub>DDHM</sub> +0.3	V
V <sub>IN</sub>	Input signal Voltage	-0.3 to 3.6	V
V <sub>out</sub>	Output signal Voltage	-0.3 to V <sub>DDHM</sub> +0.3	V
T <sub>STG</sub>	Storage Temperature	-40 to 150	°C

# **Recommended Operating Conditions**

SYMBOL	PARAMETER	MIN	ТҮР	МАХ	UNITS
V <sub>DDHM</sub>	Power Supply	3.0	3.3	3.6	V
V <sub>DD</sub>	Digital Supply	1.62	1.8	1.98	V
V <sub>IN</sub>	Input signal Voltage	0	3.3	3.6	V
T <sub>OPR</sub>	Operating Temperature	0		70	°C

### **General DC Characteristics**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	мах	UNITS
$I_{IN}$	Input current	no pull-up or pull-down	-10	±1	10	μА
I <sub>OZ</sub>	Tri-state leakage current		-10	±1	10	μА
C <sub>IN</sub>	Input capacitance	Pad Limit		2.8		ρF
Соит	Output capacitance	Pad Limit		2.8		ρF
C <sub>BID</sub>	Bi-directional buffer capacitance	Pad Limit		2.8		ρF

### DC Electrical Characteristics of 3.3V I/O Cells

CVMBOL	PARAMETER	CONDITIONS	Limits			LINIT
SYMBOL			MIN	TYP	MAX	UNIT
V <sub>DDHM</sub>	Power supply	3.3V I/O	3.0	3.3	3.6	V
V <sub>il</sub>	Input low voltage	IVITI			0.8	٧
V <sub>ih</sub>	Input high voltage	LVTTL	2.0			٧
V <sub>ol</sub>	Output low voltage	I <sub>ol</sub>   =2~16mA			0.4	V
V <sub>oh</sub>	Output high voltage	I <sub>oh</sub>   =2~16mA	2.4			V
R <sub>pu</sub>	Input pull-up resistance	PU=high, PD=low	55	75	110	ΚΩ
R <sub>pd</sub>	Input pull-down resistance	PU=low, PD=high	40	75	150	ΚΩ
I <sub>in</sub>	Input leakage current	V <sub>in</sub> = V <sub>DDHM</sub> or 0	-10	±1	10	μ Α
I <sub>oz</sub>	Tri-state output leakage current		-10	±1	10	μΑ

### **Electrical Characteristics**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
VD33	Analog supply voltage		3.0	3.3	3.6	٧
VDDA VDDU	Digital supply voltage		1.62	1.8	1.98	V
Icc	Operating supply current	High speed operating at 480 MHz			55	mA
I <sub>CC(susp)</sub>	Suspend supply current	In suspend mode, current with 1.5kΩ pull-up resistor on pin RPU			120	μА

Above technical information is based on industry standard data and tested to be reliable. However, Transcend makes no warranty, either expressed or implied, as to its accuracy and assumes no liability in connection with the use of this product. Transcend reserves the right to make changes in specifications at any time without prior notice.